

ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 200 A



ADD-A-PAK

PRODUCT SUMMARY				
I _{F(AV)}	200 A			
V _R	100 V			
Package	ADD-A-PAK			
Circuit	Two diodes doubler circuit			

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple

package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- · High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VSKDS403.. Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	200	Α			
V _{RRM}		100	V			
I _{FSM}	t _p = 5 μs sine	25 500	Α			
V _F	100 A _{pk} , T _J = 125 °C	0.66	V			
T _J	Range	- 55 to 175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VSKDS403/100	UNITS		
Maximum DC reverse voltage	V_{R}	100	V		
Maximum working peak reverse voltage	V_{RWM}	100	V		



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS		UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 111 °C, rectangular waveform		200	
Maximum peak one cycle	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	25 500	Α
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	3300	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 5.5 \text{A}, L = 1 \text{mH}$		15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} -	200 A	T _J = 25 °C	0.99	V
Maximum forward voltage drop		400 A		1.3	
Maximum forward voltage drop		200 A	T _J = 125 °C	0.83	
		400 A		1.09	
Maximum vayayaa laakaga ayyyaat		T _J = 25 °C	V _R = Rated V _R	6	A
Maximum reverse leakage current	I _{RM}	T _J = 125 °C		80	mA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		55 000	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	I 50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.26	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	C/VV
Approximate weight				75	g
				2.7	OZ.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
Mounting torque ± 10 /6	busbar		spread of the compound.	3	INIII
Case style			JEDEC	TO-240AA co	ompatible





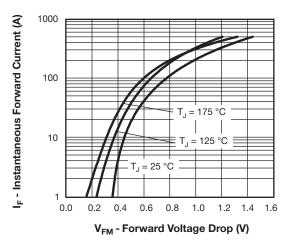


Fig. 1 - Maximum Forward Voltage Drop Characteristics

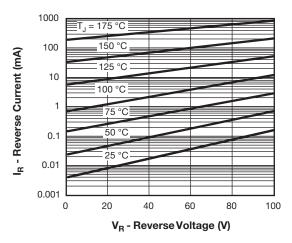


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

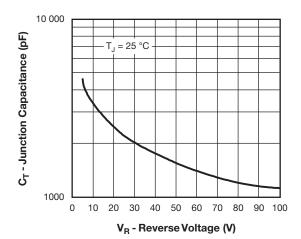


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

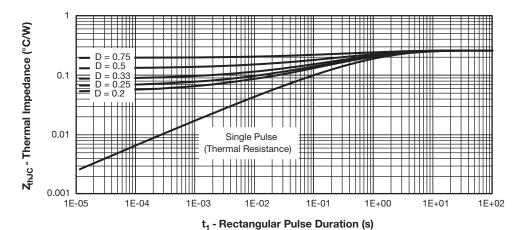


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

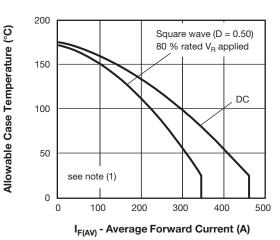


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

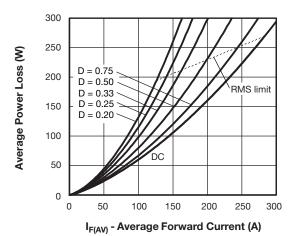


Fig. 6 - Forward Power Loss Characteristics

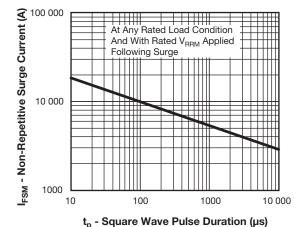


Fig. 7 - Maximum Non-Repetitive Surge Current

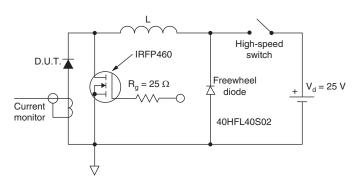


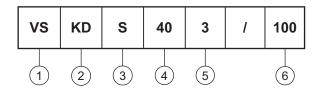
Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

KD = ADD-A-PAK - 2 diodes in series

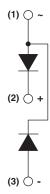
3 - S = Schottky diode

4 - Average rating (x 10)

5 - Product silicon identification

6 - Voltage rating (100 = 100 V)

CIRCUIT CONFIGURATION

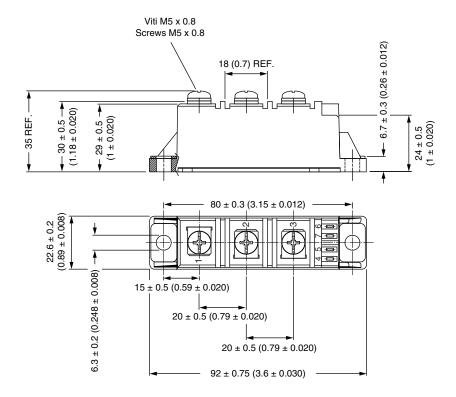


Γ	LINKS TO RELATED DOCUMENTS			
	Dimensions	www.vishay.com/doc?95369		



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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